



Precision Wide Bandwidth LanSwitch Quad 2:1 Mux/DeMux

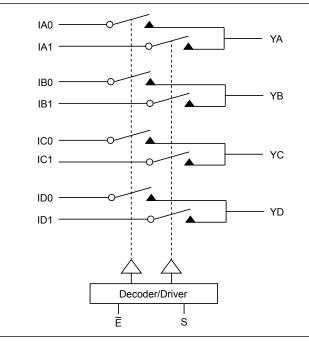
Features

- → Single 3.3V/5V supply operation
- → Rail-To-Rail Operation
- → Very Low Distortion: 2%
- → Replaces mechanical relays
- → High-performance, low-cost solution for switching between different LAN signals
- → Low crosstalk: -70dB @ 30 Mbps
- → Low insertion loss and On-Resistance: 6-ohms typical
- → Off isolation: -55dB @ 30 Mbps
- → Wide bandwidth data rates >135 Mbps
- → Low Quiescent Supply Current (100nA typical)
- → Packaging (Pb-free & Green available):
 - 16-pin 150-mil wide plastic QSOP (Q)
 - 16-pin 150-mil wide plastic SOIC (W)
 - 16-pin 173-mil wide plastic TSSOP (L)

Applications

- → 10/100 Base-TX/T4
- → 100VG-AnyLAN
- → Token Ring 4/16 Mbps
- → ATM25
- → NIC Adapter and Hubs
- → SONET OCI 51.8Mbps
- → T1/E1

Block Diagram

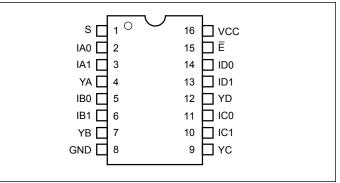


Description

Diodes' PI5L200 is a Rail-to-Rail Quad 2:1 multiplexer/demultiplexer LanSwitch with 3-state outputs. The On-Resistance typically varies from 5 ohms to 7 ohms with data inputs of 0V to 5V. Generally, this part can be used to replace mechanical relays in low voltage (3.3V/5V systems) LAN applications.

With a wide bandwidth of 135 MHz, the PI5L200 can switch Fast Ethernet and ATM25 signals. Into 100-ohm UTP cables, the switch distortion is typically less than two percent. Crosstalk @30 MHz is -70dB. The PI5L200 operates from a single 3.3V/5V supply and interface to TTL logic.

Pin Configuration



Pin Description

Pin Name	Description
IAn-IDn	Data Inputs
S	Select Inputs
Ē	Enable
YA-YD	Data Outputs
GND	Ground
V _{CC}	Power

Truth Table

Ē	S	YA	YB	YC	YD	Function
Н	Х	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Disable
L	L	IA0	IB0	IC0	$_{\rm I} {\rm D}_0$	S = 0
L	Н	IA1	IB1	_I C ₁	$_{I}D_{1}$	S = 1

Note:

H = High Voltage Level,

L = Low Voltage Level, S

witches are shown with logic "0" input (Select and Enable)

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Note:



PI5L200

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

· · · ·	<u> </u>
Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	40°C to +85°C
Supply Voltage to Ground Potential	-0.5V to +7.0V
DC Input Voltage	
DC Output Current	120 mA
Power Dissipation	

Stresses greater than those listed under MAXIMUM RAT-INGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Single 5.0V Supply

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 5V \pm 10\%$, GND = 0V)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
VANALOG	Analog Signal Range		0	—	V _{CC}	V
R _{ON}	ON-Resistance	$I_{ON} = 10 \text{mA} \text{ to } 30 \text{mA}$	_	6	12	
ΔR_{ON}	Match Between Channels		_	0.4	2	Ω
R _{FLAT(ON)}	R _{ON} Flatness	$I_{ON} = 1 \text{ mA}, V_{NO}, V_{NC} = 0 \text{ V to } 5 \text{ V}$	_	3	5	
I _{NO(OFF)} , I _{NO(ON)}	On/Off Leakage Current	$V_{\rm NO}, V_{\rm NC} = 4.5 V$	-100	_	100	nA
I _{CC}	Quiescent Supply Current	$V_{CC} = 5.5 V$, $V_{IN} = 0 V$ or V_{CC}	_	_	1	μΑ
IO	Output Current	V_{NO} , V_{NC} or $V_{COM} = 0V$ to 5V	100	_		mA
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	_	_	V
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5	_	0.8	V
I _{IH}	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	_	_	±1	
I _{IL}	Input LOW Current	$V_{CC} = Max., V_{IN} = GND$	_	_	±1	μA

Dynamic Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 5V \pm 10\%$, GND = 0V)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
t _{ON}	Turn-on Time	V_{ON} or $V_{NC} = 3.0V$, see Fig. 2	_	10	20	
t _{OFF}	Turn-off Time	V_{ON} or $V_{NC} = 3.0V$, see Fig. 2	_	5	10	ns
X _{TALK}	Crosstalk	$R_L = 100$ ohms, f = 30 MHz, see Fig. 4	_	-70	_	dB
C _(OFF)	NC or NO Capacitance	f = 1 kHz	_	13	_	pF
O _{IRR}	Off Isolation	$R_L = 100$ ohms, f = 30 MHz, see Fig. 5	_	-55	_	dB
BW	Bandwidth -3dB	$R_L = 100$ ohms, see Fig. 3	_	137	_	MHz
D	Distortion DR _{ON} /RL	$R_L = 100 \text{ ohms}$	_	2	_	%

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for applicable device type.

2. Guaranteed by design.





Single 3.3V Supply

DC Electrical C	haracteristics (Over the Op	perating Range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, V	CC = 3.3V	±10%, GN	D = 0V	

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
VANALOG	Analog Signal Range		0	_	V _{CC}	V
R _{ON}	ON-Resistance	$I_{ON} = 10 \text{mA} \text{ to } 30 \text{mA}$	_	15	22	
ΔR_{ON}	Match Between Channels		_	1	3	Ω
R _{FLAT(ON)}	R _{ON} Flatness	$I_{ON} = 1 \text{ mA}, V_{NO}, V_{NC} = 0 \text{ V to } 5 \text{ V}$	_	7	12	
I _{NO(OFF)} , I _{NO(ON)}	On/Off Leakage Current	$V_{\rm NO}, V_{\rm NC} = 3.0 V$	-100	_	100	nA
I _{COM(ON)}	On Leakage Current	V_{NO} , $V_{NC} = 3.0V$	-100	_	100	μA
IO	Output Current	V_{NO} , V_{NC} or $V_{COM} = 0V$	80	_	—	mA
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	_	—	v
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5	_	0.8	l v
I _{IH}	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	_	_	±1	
I _{IL}	Input LOW Current	$V_{CC} = Max., V_{IN} = GND$	_	_	±1	μΑ

Dynamic Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = 3.3V \pm 10\%$, GND = 0V)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
t _{ON}	Turn-on Time	V_{ON} or $V_{NC} = 1.5V$, see Fig. 2	_	28	40	
t _{OFF}	Turn-off Time	V_{ON} or $V_{NC} = 1.5V$, see Fig. 2	_	4	20	ns
X _{TALK}	Crosstalk	$R_L = 50$ ohms, $f = 1$ MHz, see Fig. 4	-	-75	_	dB
C _(OFF)	NC or NO Capacitance	f = 1 kHz	_	15	_	Б
C _{COM(OFF)}	COM Off Capacitance	f = 1 kHz	_	30	_	pF
O _{IRR}	Off Isolation	$R_L = 50$ ohms, $f = 1$ MHz, see Fig. 5	_	-75	_	dB
BW	Bandwidth -3dB	$R_L = 50$ ohms, see Fig. 3	_	110	_	MHz
D	Distortion	$R_L = 100 \text{ ohms}$	_	4	_	%

Dynamic Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = 3.3V \pm 10\%$, GND = 0V)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I _{CC}	-	$V_{CC} = 3.6V$, $V_{IN} = 0V$ or V_{CC} All Channesl ON or OFF	_		1	μΑ

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for applicable device type.

2. Guaranteed by design.





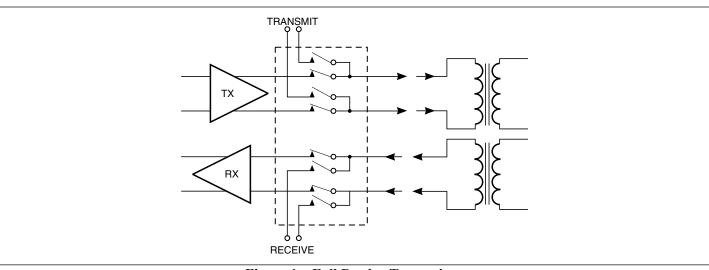


Figure 1a. Full Duplex Transceiver

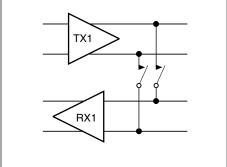
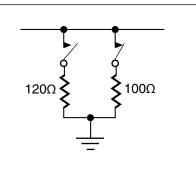


Figure 1b. Loop Back



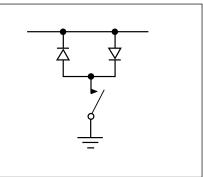


Figure 1c. Line Termination

Figure 1d. Line Clamp

Test Circuits

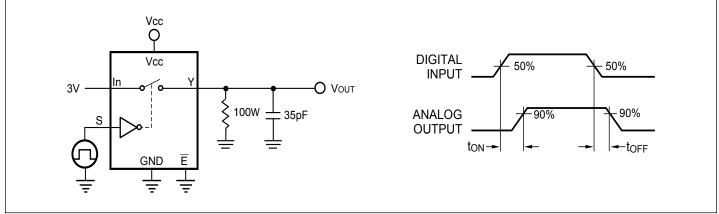


Figure 2. Switching Time





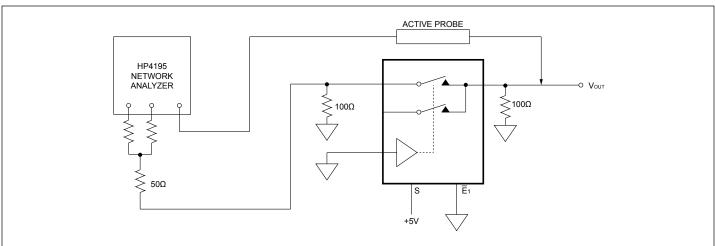


Figure 3. Bandwidth

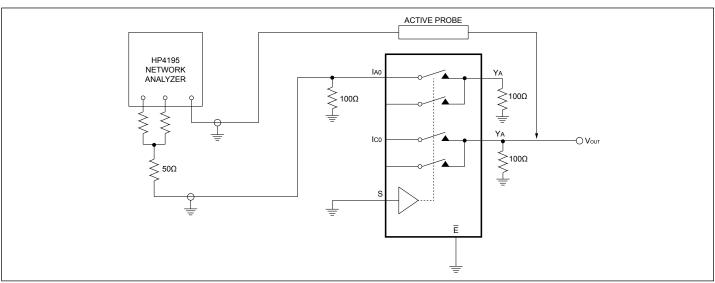
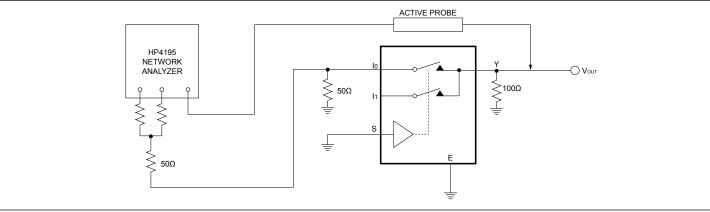


Figure 4. Crosstalk









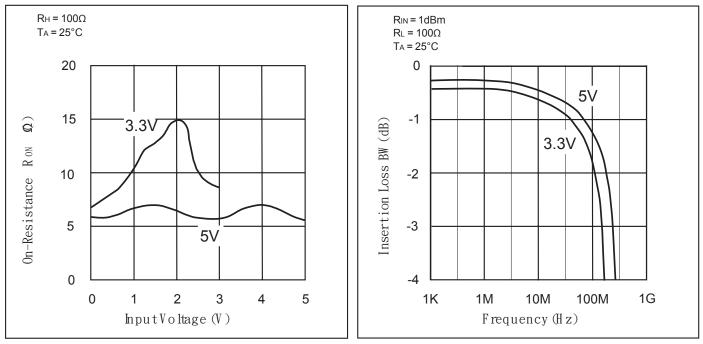


Figure 6. On-Resistance vs. Input Voltage

Figure 7. Insertion Loss vs. Frequency

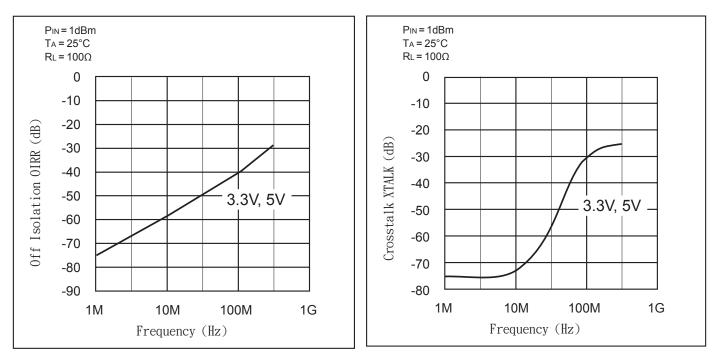


Figure 8. Off Isolation vs. Frequency







Part Marking

Q Package



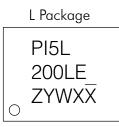
Z: Die Rev Code Y: Year W: Workweek 1st X: Assembly Code 2nd X: Fab Code

W Package



B: Port Code Z: Die Rev YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code

PI5L200

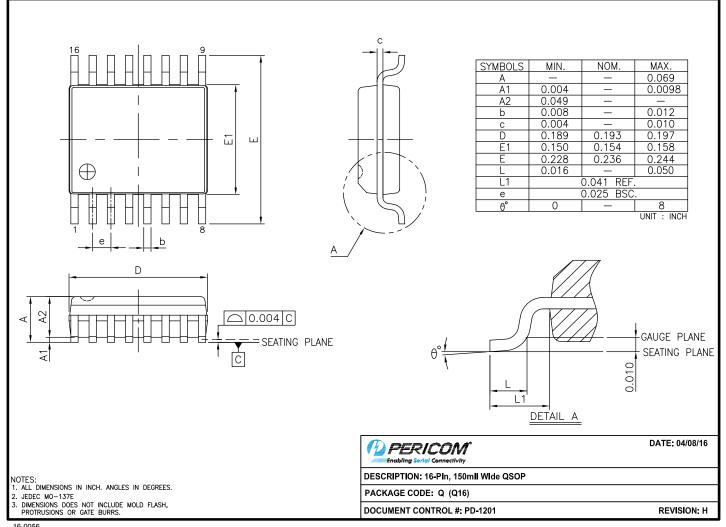


Z: Die Rev Y: Year W: Workweek 1st X: Assembly Code 2nd X: Fab Code





Packaging Mechanical: 16-QSOP(Q)



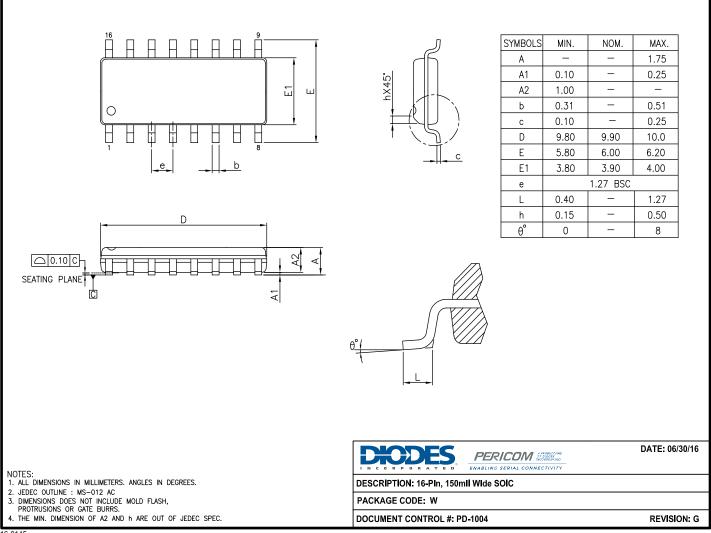
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Packaging Mechanical: 16-SOIC (W)

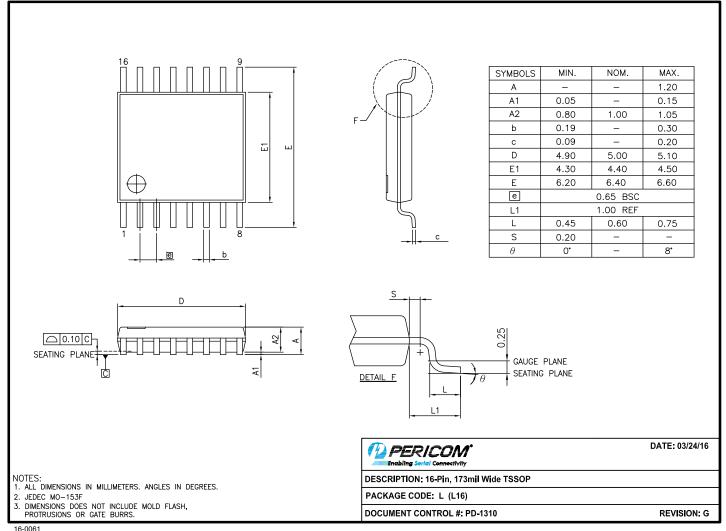


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Packaging Mechanical: 16-TSSOP(L)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Packaging Code	Package Description
PI5L200QEX	Q	16-pin, 150mil Wide (QSOP)
PI5L200WEX	W	16-pin, 150mil Wide (SOIC)
PI5L200LEX	L	16-pin, 173mil Wide (TSSOP)

Notes:

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1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

3. E = Pb-free and Green

4. X suffix = Tape/Reel





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